

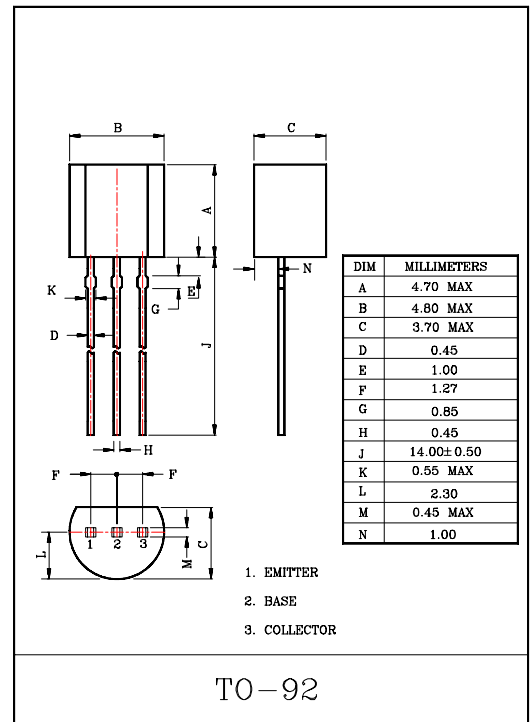
GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

FEATURES

- Low Leakage Current
: $I_{CEX}=10\text{nA}(\text{Max.})$; $V_{CE}=60\text{V}$, $V_{EB}(\text{OFF})=3\text{V}$.
- Low Saturation Voltage
: $V_{CE(\text{sat})}=0.3\text{V}(\text{Max.})$; $I_C=150\text{mA}$, $I_B=15\text{mA}$.
- Complementary to the KTN2907/2907A.
- KTN2222/2222A Electrically Similar to 2N2222/2222A.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING		UNIT
		KTN2222	KTN2222A	
Collector-Base Voltage	V_{CBO}	60	75	V
Collector-Emitter Voltage	V_{CEO}	30	40	V
Emitter-Base Voltage	V_{EBO}	5	6	V
Collector Current	I_C	600		mA
Collector Power Dissipation ($T_a=25^\circ\text{C}$)	P_C	625		mW
Junction Temperature	T_j	150		$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55 \sim 150$		$^\circ\text{C}$



KTN2222/A

ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	KTN2222A	I_{CEX}	$V_{CE}=60V, V_{EB(OFF)}=3V$	–	–	10	nA
Collector Cut-off Current	KTN2222	I_{CBO}	$V_{CB}=50V, I_E=0$	–	–	0.01	μA
	KTN2222A		$V_{CB}=60V, I_E=0$	–	–	0.01	
Emitter Cut-off Current	KTN2222A	I_{EBO}	$V_{EB}=3V, I_C=0$	–	–	10	nA
Collector - Base Breakdown Voltage	KTN2222	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	60	–	–	V
	KTN2222A			75	–	–	
Collector-Emitter Breakdown Voltage *	KTN2222	$V_{(BR)CEO}$	$I_E=10mA, I_B=0$	30	–	–	V
	KTN2222A			40	–	–	
Emitter-Base Breakdown Voltage	KTN2222	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	5	–	–	V
	KTN2222A			6	–	–	
DC Current Gain *	KTN2222 KTN2222A	$h_{FE(1)}$	$I_C=0.1mA, V_{CE}=10V$	35	–	–	
		$h_{FE(2)}$	$I_C=1mA, V_{CE}=10V$	50	–	–	
		$h_{FE(3)}$	$I_C=10mA, V_{CE}=10V$	75	–	–	
		$h_{FE(4)}$	$I_C=150mA, V_{CE}=10V$	100	–	300	
	KTN2222 KTN2222A	$h_{FE(5)}$	$I_C=500mA, V_{CE}=10V$	30	–	–	
				40	–	–	
Collector-Emitter Saturation Voltage *	KTN2222	$V_{CE(sat)1}$	$I_C=150mA, I_B=15mA$	–	–	0.4	V
	KTN2222A			–	–	0.3	
	KTN2222	$V_{CE(sat)2}$	$I_C=500mA, I_B=50mA$	–	–	1.6	
	KTN2222A			–	–	1	
Base-Emitter Saturation Voltage *	KTN2222	$V_{BE(sat)1}$	$I_C=150mA, I_B=15mA$	–	–	1.3	V
	KTN2222A			0.6	–	1.2	
	KTN2222	$V_{BE(sat)2}$	$I_C=500mA, I_B=50mA$	–	–	2.6	
	KTN2222A			–	–	2.0	
Transition Frequency	KTN2222	f_T	$I_C=20mA, V_{CE}=20V, f=100MHz$	250	–	–	MHz
	KTN2222A			300	–	–	
Collector Output Capacitance		C_{ob}	$V_{CB}=10V, I_E=0, f=1.0MHz$	–	–	8	pF
Input Capacitance	KTN2222	C_{ib}	$V_{EB}=0.5V, I_C=0, f=1.0MHz$	–	–	30	pF
	KTN2222A			–	–	25	

*Pulse Test : Pulse Width $\leq 300\mu S$, Duty Cycle $\leq 2.0\%$

KTN2222/A

ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Impedance	KTN2222A	h_{ie}	$I_C=1mA, V_{CE}=10V, f=1kHz$	2	–	8	$k\Omega$
			$I_C=10mA, V_{CE}=10V, f=1kHz$	0.25	–	1.25	
Voltage Feedback Ratio	KTN2222A	h_{re}	$I_C=1mA, V_{CE}=10V, f=1kHz$	–	–	8	$\times 10^{-4}$
			$I_C=10mA, V_{CE}=10V, f=1kHz$	–	–	4	
Small-Signal Current Gain	KTN2222A	h_{fe}	$I_C=1mA, V_{CE}=10V, f=1kHz$	50	–	300	
			$I_C=10mA, V_{CE}=10V, f=1kHz$	75	–	375	
Collector Output Admittance	KTN2222A	h_{oe}	$I_C=1mA, V_{CE}=10V, f=1kHz$	5	–	35	μS
			$I_C=10mA, V_{CE}=10V, f=1kHz$	25	–	200	
Collector-Base Time Constant	KTN2222A	$C_c \cdot r_{bb'}$	$I_E=20mA, V_{CB}=20V, f=31.8MHz$	–	–	150	pS
Noise Figure	KTN2222A	NF	$I_C=100\mu A, V_{CE}=10V, R_g=1k\Omega, f=1kHz$	–	–	4	dB
Switching Time	Delay Time	t_d	$V_{CC}=30V, V_{BE(OFF)}=0.5V$ $I_C=150mA, I_{B1}=15mA$	–	–	10	nS
	Rise Time	t_r		–	–	25	
	Storage Time	t_{stg}	$V_{CC}=30V, I_C=150mA$ $I_{B1}=-I_{B2}=15mA$	–	–	225	
	Fall Time	t_f		–	–	60	

